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## High-temperature oxidation kinetics of nanostructured thermoelectric skutterudite $\text{CoSb}_3$ under different environments†

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Skutterudite  $\text{CoSb}_3$  is an n-type thermoelectric material used in thermoelectric generators (TEGs) to recover and convert heat from various sources into electricity. For TEGs, such as  $\text{CoSb}_3$ , thermal stability is crucial, especially when exposed to high temperatures and varying environments. To synthesize high-purity nanostructured  $\text{CoSb}_3$ , an optimized solvothermal method was developed with detailed investigation of the influence of stoichiometry, solvent choice, and reaction duration on the formation mechanism, as revealed by Powder X-ray diffraction (PXRD). The thermal degradation behavior of the synthesized  $\text{CoSb}_3$  was systematically analyzed in air and nitrogen atmosphere. The oxidation products were identified using PXRD, the microstructural changes and morphological evolution during oxidation were examined using SEM (Scanning Electron Microscopy) and TEM (Transmission Electron Microscopy). Oxidation kinetics were determined using a nonlinear integral isoconversional method. This study revealed the formation of multiple oxides of Co and Sb at higher temperature and interconversion of these oxides after secondary reaction and follows a different kinetics in air and  $\text{N}_2$  atmosphere due to the changes in the degradation mechanism.

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### Introduction

Thermoelectric generators (TEG) have emerged as a promising solution to combat the global energy crisis because of their ability to directly convert heat to electricity and recover energy lost as heat from various sources.<sup>1,2</sup> These TEGs can efficiently recover heat from sources such as industrial processes, power plants, exhaust pipes, and internal combustion (IC) engines of automobiles to reduce gas emissions and control global warming. The tunable figure of merit ( $zT$ ), mechanical stability, and affordability makes  $\text{CoSb}_3$  an ideal thermoelectric (TE) material for efficient heat recovery in automotive exhaust pipes through planar and tubular ring-shaped TEGs.<sup>3–5</sup>  $\text{CoSb}_3$ , with its skutterudite structure belonging to the cubic space group  $Im\bar{3}$  features intrinsic voids that allow the insertion of foreign atoms. These foreign atoms act as rattling centers, thereby scattering lattice phonons to reduce thermal conductivity and enhance TE efficiency.<sup>6,7</sup> Hence, filled skutterudite structures possess immense potential for performance enhancement, attracting wide research attention with extensive studies actively exploring such possibilities.<sup>8–11</sup>

$\text{CoSb}_3$  can be synthesized through feasible chemical methods such as sol-gel,<sup>12</sup> polyol,<sup>13</sup> and solvothermal methods<sup>14</sup> utilising  $\text{CoCl}_2 \cdot 6\text{H}_2\text{O}$  and  $\text{SbCl}_3$  as precursors. Among these methods, the solvothermal method offers feasible low-temperature synthesis in addition to cost efficiency. The solvothermal method yields highly crystalline compounds and facilitates easy tuning of the morphology of the materials. However, one of the drawbacks of using the solvothermal method for  $\text{CoSb}_3$  synthesis is the formation of the side products  $\text{CoSb}_2$  and  $\text{Sb}$ .<sup>14,15</sup> To address this issue we optimized the solvothermal method by tuning parameters such as reactant concentration, reaction duration, and solvent choice to synthesize high-purity  $\text{CoSb}_3$ .  $\text{CoSb}_3$  is intended for use in the 150–600 °C region and thermal stability in this region is a crucial requirement for its application in various devices.<sup>16,17</sup>  $\text{CoSb}_3$  remains thermally stable up to 400 °C, above this temperature, the oxidation of  $\text{CoSb}_3$  and sublimation of the resulting  $\text{Sb}$  leads to degradation of the material. Above 400 °C, the possibility of formation of compounds such as  $\text{Co}_3\text{O}_4$ ,  $\text{CoO}$ ,  $\text{Sb}_2\text{O}_3$ ,  $\text{Sb}_2\text{O}_4$ ,  $\text{Sb}_2\text{O}_5$ ,  $\text{Sb}_6\text{O}_{13}$ , and higher oxides such as  $\text{CoSb}_2\text{O}_6$  and  $\text{CoSb}_2\text{O}_4$  leads to a complicated Co-Sb-O phase system in the working temperature range.<sup>18</sup> However, a thermoelectric material should be stable in the operational temperature range without losing its stoichiometry or integrity.

According to the literature, when  $\text{CoSb}_3$  synthesized by spark plasma sintering is aged at high temperatures, it forms two-layered oxide films comprising antimony oxides and cobalt-antimony oxides. The thickness of these films increases as the

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temperature rises from 500 °C to 700 °C.<sup>17,19</sup> Further studies showed that CoSb<sub>3</sub> oxidation followed a parabolic rate law and the activation energy for oxidation was calculated as 37.4 kJ mol<sup>-1</sup>.<sup>18</sup> In a helium atmosphere, CoSb<sub>3</sub> decomposed in multiple stages, beginning at 420 °C.<sup>20</sup> The activation energy of CoSb<sub>3</sub> decomposition in an argon atmosphere was reported to be 200 kJ mol<sup>-1</sup>.<sup>21</sup> The thermal stability and decomposition kinetics of CoSb<sub>3</sub> and filled CoSb<sub>3</sub> synthesized using methods such as spark plasma sintering, ball milling,<sup>22</sup> and annealing<sup>23</sup> have been well-studied, whereas studies on the thermal stability and decomposition of CoSb<sub>3</sub> synthesized by the solvothermal method are relatively scarce. The solvothermal method is an efficient method for the synthesis of CoSb<sub>3</sub> highlighting the need to study the thermal stability and decomposition kinetics of CoSb<sub>3</sub> synthesized using the solvothermal method.

We evaluated the thermal stability, degradation mechanism, and kinetics of CoSb<sub>3</sub> in air and nitrogen (N<sub>2</sub>) atmospheres over a temperature range of 30–700 °C using thermogravimetric analysis (TGA). Weight gain followed by weight loss was observed in the thermogravimetric analysis, necessitating a detailed study of the underlying processes. TGA was performed in air at various heating rates and the underlying kinetics of these processes were studied using a nonlinear integral isoconversional method. The probable processes and microstructural changes in this region were investigated using Powder X-ray diffraction (PXRD), Scanning Electron Microscopy (SEM), and Transmission Electron Microscopy (TEM).

## Experimental methods

### Materials

Cobalt chloride hexahydrate (CoCl<sub>2</sub>·6H<sub>2</sub>O), antimony trichloride (SbCl<sub>3</sub>), and sodium borohydride (NaBH<sub>4</sub>) used for the synthesis were obtained from SRL Pvt. Ltd, and methanol (CH<sub>3</sub>OH) was obtained from Thermo Fisher India Pvt. Ltd. All chemicals were used without further purification.

### Synthesis of high-purity CoSb<sub>3</sub> nanostructures

The solvothermal method was optimized for the synthesis of high-purity CoSb<sub>3</sub> nanostructures (CNS).<sup>14</sup> The precursors, cobalt chloride hexahydrate (CoCl<sub>2</sub>·6H<sub>2</sub>O) and antimony trichloride (SbCl<sub>3</sub>) were dissolved in 10 mL ethanol at various concentrations. NaBH<sub>4</sub> dissolved in 5 mL of deionized (DI) water was added dropwise to the precursor solution and the reaction was allowed to continue for 15 min. The obtained suspension was transferred to a PPL-lined autoclave and heated to the desired temperature in a muffle furnace. The stoichiometric ratio of the precursors, reaction duration, and solvents were systematically varied to obtain high-purity nanostructured CoSb<sub>3</sub>. The products obtained were washed thoroughly with water and ethanol, dried at 100 °C for 5 h, and used for further analysis.

### Structural characterization

PXRD analysis of the synthesized CoSb<sub>3</sub> nanostructures was carried out using a Malvern Panalytical X'Pert<sup>3</sup> X-ray

diffractometer between 2θ values of 20° and 70° at a step size of 0.013° using Cu Kα (1.54 Å) radiation. The data were analyzed using the X'Pert HighScore Plus software with the International Centre for Diffraction Data (ICDD) database. The detailed internal structure, including the crystal structure and orientation, was analyzed by TEM. TEM images were recorded on a JEOL JEM F200 transmission electron microscope with the samples dispersed in methanol and drop-cast over carbon-coated copper TEM grids. The particle size and SAED patterns were analyzed using Gatan Digital Microscopy Suite software.

### Surface characterisation

The surface morphologies of the particles were analyzed using SEM. SEM images were recorded using a ZEISS Gemini 1 Sigma 300 scanning electron microscope. To record SEM images of the CNS, the sample was dispersed in methanol and drop casted onto a glass slide. A high-resolution secondary electron image of CNS was obtained using an in-lens detector placed inside the electron column. The particle size was determined from the SEM images using ImageJ software. X-ray Photoelectron Spectroscopy (XPS) was performed using a Shimadzu Axis Supra+, X-ray Photoelectron Spectrometer equipped with a microfocused monochromatic Al Kα source ( $h\nu = 1486.6$  eV). The C 1s peak (284.8 eV) was used as the reference peak, and data deconvolution was performed using XPSpeak41 software.

### Thermal stability analysis

The thermal stability of the synthesized compounds was studied using TGA. TGA experiments were performed on a TA Instruments Q50 Thermogravimetric Analyzer in the temperature range of 30 to 700 °C at a heating rate of 10 °C min<sup>-1</sup> under air and N<sub>2</sub> atmosphere.

### Kinetic analysis

A nonlinear integral isoconversional (model-free) method, Vyazovkin's method, was employed for the computation of kinetic parameters and kinetic analysis. The third-degree approximation proposed by Senum and Yang<sup>24</sup> was used in this study to evaluate the integral in Vyazovkin's method. The detailed kinetic computation procedures are provided in the ESI.† For the kinetic calculations, the TGA data obtained under an air flow (40 mL min<sup>-1</sup>) at heating rates of 4, 6, 8, and 10 °C min<sup>-1</sup> were utilized. In all experiments, approximately 1.5 mg sample was loaded into a platinum pan and heated at the desired heating rates.

### Residue analysis

The TG analysis residue in air and N<sub>2</sub> atmosphere was collected at different stages, such as the sample heated up to the temperature of maximum weight gain, the sample heated to the temperature of maximum weight loss, and the sample heated up to 700 °C. The SEM images of residue samples were recorded using powder samples, and PXRD analysis was performed by maintaining a step size of 0.026 in the 2θ range of 20° to 70°.



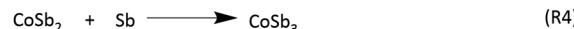
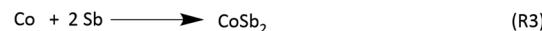
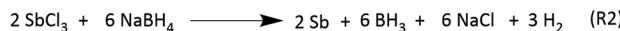
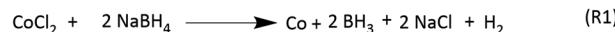
## Results and discussions

### Chemical synthesis and characterization of high-purity nanostructured $\text{CoSb}_3$

Considering the theoretical stoichiometric ratio (1 : 3),  $\text{CoSb}_3$  synthesis was initiated by mixing stoichiometric amounts of the precursors in 10 mL of ethanol. The reducing agent  $\text{NaBH}_4$  (nine equivalents) solution was added dropwise to the precursor solution. The obtained colloid was transferred to a PPL-lined autoclave and heated at 240 °C for 96 h. Analysis of the PXRD data (Fig. 1(a)) revealed that when the concentration was at a stoichiometric ratio (1 : 3), peaks corresponding to Sb (ICDD 01-085-1322) and  $\text{CoSb}_3$  (ICDD 01-078-0976) were observed.

As shown in Scheme 1, the formation of  $\text{CoSb}_3$  proceeds in several steps, starting with the reduction of the Co and Sb precursors, which subsequently leads to the formation of  $\text{CoSb}_2$  and  $\text{CoSb}_3$ . Assuming the excess concentration of  $\text{SbCl}_3$  as a probable cause of Sb formation, the concentration of  $\text{SbCl}_3$  was varied in a series of reactions with Co : Sb ratios of 1 :  $x$  ( $x = 2.5, 2.75, 2.8$ , and 3). The details of the stoichiometric ratio variations are presented in Table 1. All obtained samples were characterized using PXRD for phase identification and purity confirmation. The diffraction pattern revealed the presence of the  $\text{CoSb}_2$  impurity phase (ICDD 00-029-0126) in all samples.

Given the potent reducing power of  $\text{NaBH}_4$ , its addition immediately triggered rapid reduction of  $\text{CoCl}_2$  and  $\text{SbCl}_3$  to generate  $\text{Co}^0$  and  $\text{Sb}^0$ . The significant decrease in the number of



Scheme 1 A probable mechanism for the stepwise formation of  $\text{CoSb}_3$  from its constituents.<sup>15</sup>

peaks of  $\text{CoSb}_2$  from 1 : 2.5 equivalents to 1 : 2.75 equivalents shows a greater extent of reaction between  $\text{CoSb}_2$  and Sb with increasing concentration of  $\text{SbCl}_3$ . Hence, the analysis indicated that the reaction between  $\text{CoSb}_2$  and Sb (R4, Scheme 1) controls the formation of  $\text{CoSb}_3$ . Upon further increasing the  $\text{SbCl}_3$  concentration from 2.75 to 2.8 equivalents the intensity of the  $\text{CoSb}_2$  peaks decreased (Fig. 1(b)). The appearance of  $\text{CoSb}_2$  peaks from 2.5 to 2.8 equivalents indicates that  $\text{SbCl}_3$  is the limiting reactant. As Sb impurities were detected at 1 : 3 reactant ratio (Fig. 1(c)), we optimized the stoichiometric ratio of 1 : 2.8 equivalents of reactants to achieve high-purity CNS.

To further optimize the reaction and understand the influence of the reaction duration on the formation of  $\text{CoSb}_3$ , the reaction was carried out for different durations using a precursor ratio of 1 : 2.8 which resulted in a minimal amount of impurities. The products formed immediately after the addition of  $\text{NaBH}_4$  (at RT) and from the set of reactions performed at 240 °C for various durations (24, 48, 72, and 96 h) were analyzed using PXRD (Fig. 2(a)). The data for the precipitate obtained immediately after the addition of  $\text{NaBH}_4$  showed peaks of Sb (ICDD 01-085-1324), indicating the immediate reduction of  $\text{SbCl}_3$ . The Cobalt ions resulting from the reduction of  $\text{CoCl}_2$  may be present in the dissolved state in the solvent because peaks corresponding to cobalt or other intermediate compounds of cobalt were absent in the PXRD data. Further analysis revealed that  $\text{CoSb}_3$  (ICDD 01-078-0976) was formed after 24 h along with the major impurity phase  $\text{CoSb}_2$  (ICDD 00-029-0126) (Fig. 2(b)). Similar results were observed when the reaction duration was increased to 48 h. Furthermore, when the reaction duration was increased to 72 h, all the peaks corresponded to pure  $\text{CoSb}_3$ . This indicates that, within 72 h, reaction equilibrium was achieved between Sb (0) and  $\text{CoSb}_2$  for their combination to form  $\text{CoSb}_3$ . Consequently, pure  $\text{CoSb}_3$  nanostructures were obtained using a precise stoichiometric ratio of 1 : 2.8 equivalents of the reactants at 72 h. These

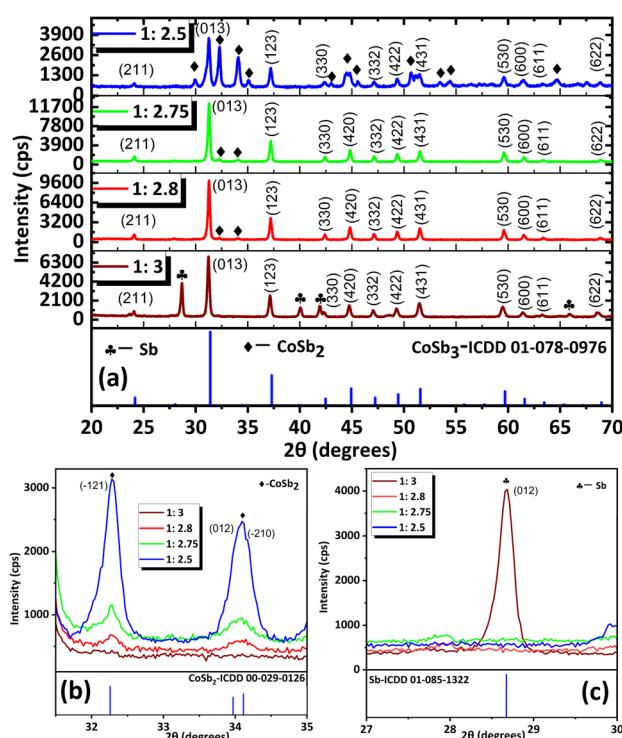


Fig. 1 (a) PXRD pattern of the  $\text{CoSb}_3$  samples obtained at different  $\text{SbCl}_3$  concentrations (the equivalents of reactants are shown in the corresponding PXRD pattern). (b)  $2\theta$  region showing  $(\bar{1}21)$ ,  $(012)$  and  $(\bar{2}10)$  peaks of  $\text{CoSb}_2$  and (c)  $2\theta$  region showing  $(012)$  peak of Sb.

Table 1 Synthesis reaction details under varying temperatures, precursor concentrations, and durations

Concentration (in equivalents)				
$\text{CoCl}_2 \cdot 6\text{H}_2\text{O}$	$\text{SbCl}_3$	$\text{NaBH}_4$	Temperature	Reaction duration
1	2.5	9	240 °C	96 hours
1	2.75	9	240 °C	96 hours
1	2.8	9	240 °C	96 hours
1	3	9	240 °C	96 hours



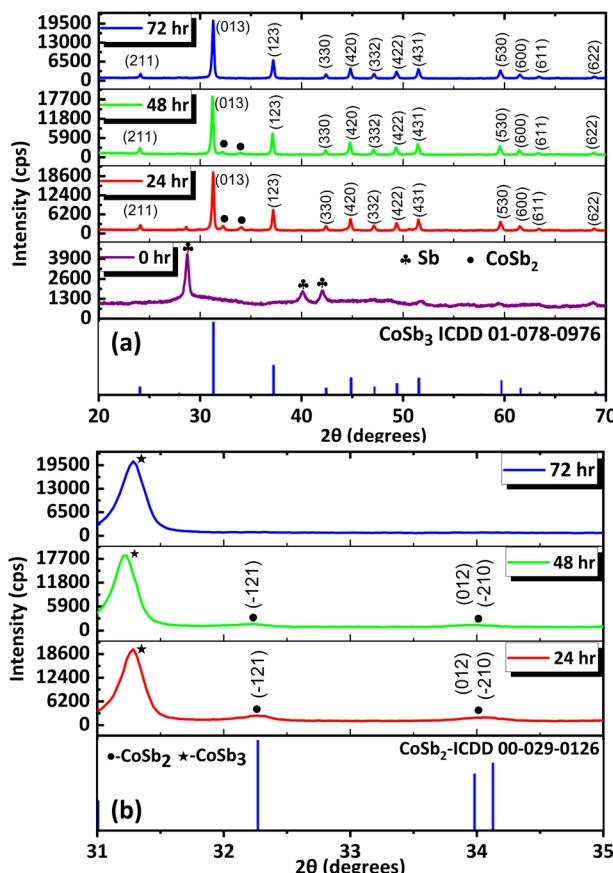
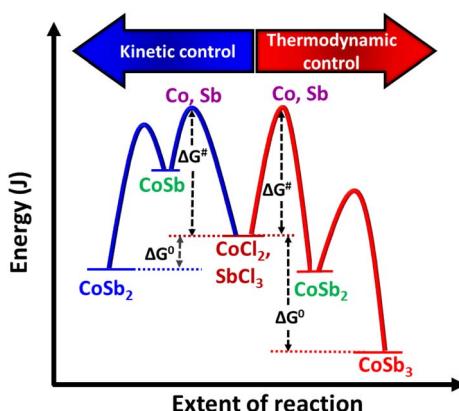


Fig. 2 (a) PXRD pattern of products obtained at different reaction durations using 1:2.8 equivalents of reactants (the reaction durations are shown in the corresponding PXRD pattern). (b) Enlarged portion showing the disappearance of (121), (012) and (210) peaks of CoSb<sub>2</sub> over time.

observations indicate that the reaction between Co and Sb to form CoSb<sub>3</sub> is thermodynamically controlled, whereas CoSb<sub>2</sub> formation is kinetically controlled (Scheme 2). The formation of CoSb<sub>3</sub> in small quantities at low Sb stoichiometries further confirms that the formation of CoSb<sub>3</sub> is thermodynamically controlled.



Scheme 2 Energy profile diagram for the formation of CoSb<sub>2</sub> and CoSb<sub>3</sub>.

The effect of the solvent on the synthesis was studied under similar reaction conditions (1:2.8 equivalents of precursors) and NaBH<sub>4</sub> (9 equivalents as reducing agent) using ethanol and methanol as the solvents at 240 °C for 72 h. Similar outcomes were anticipated because the critical temperatures of ethanol and methanol (240.75 and 239.45 °C respectively) lie nearby. However, the PXRD (Fig. 3) data of the compounds showed that while the reaction using ethanol yielded CoSb<sub>3</sub> (ICDD 01-078-0976), the reaction using methanol yielded CoSb<sub>2</sub> (ICDD 00-029-0126) as the major phase along with small amounts of CoSb<sub>3</sub>. The coexistence of the CoSb<sub>2</sub> and CoSb<sub>3</sub> phases when methanol was used as a solvent indicated that the rate of conversion of CoSb<sub>2</sub> to CoSb<sub>3</sub> was retarded. The higher polarity of methanol compared to ethanol stabilizes the CoSb<sub>2</sub> surface which in turn delays its conversion to CoSb<sub>3</sub>. Further optimization is required to achieve the complete conversion of CoSb<sub>2</sub> to CoSb<sub>3</sub> when using methanol as the reaction medium.

The SEM images of CoSb<sub>3</sub> (Fig. 4(a) and S1†), reveal particles with various sizes and morphologies that are agglomerated, indicating accelerated nucleation and growth. Cassini oval-shaped particles with sizes ranging from 40 to 70 nm were observed along with plate-like particles with sizes ranging from 100 to 150 nm. Analysis of the SEM images (Fig. 4(b-d)) of particles at 24 h, 48 h, and 72 h showed an increase in the number of plate-like particles. This is due to the rapid growth of the initially formed cassini oval-shaped particles to plate-like particles by accumulating particles on their surface to reduce their surface energy.

The TEM images of CoSb<sub>3</sub> (Fig. 5(a) and S2†) also shows agglomerated particles. Cassini oval-shaped particles of size 25–55 nm along with plate-like particles of size 100–150 nm were observed. The SAED pattern (Fig. 5(b)) exhibited single crystalline behavior with a well-defined spot pattern. The planes with *hkl* values (200), (013), (123), (330), (420), and (431) with interplanar distances of 4.5 Å, 2.8 Å, 2.4 Å, 2.1 Å, 2 Å, and 1.7 Å

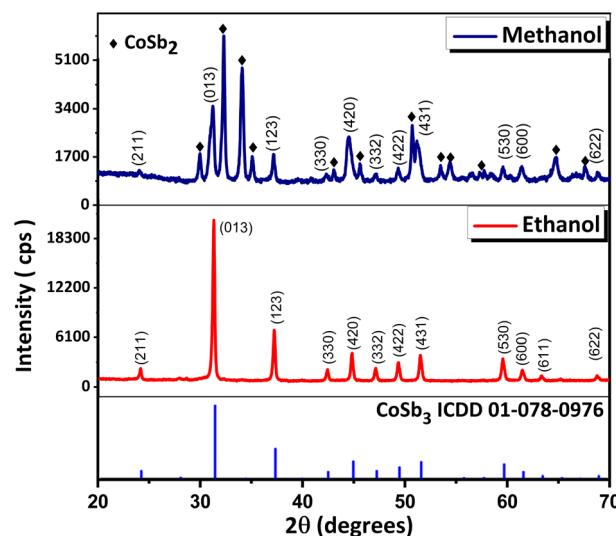


Fig. 3 PXRD pattern of products obtained in reactions using 1:2.8 equivalents of reactants for 72 h with ethanol and methanol as solvent.



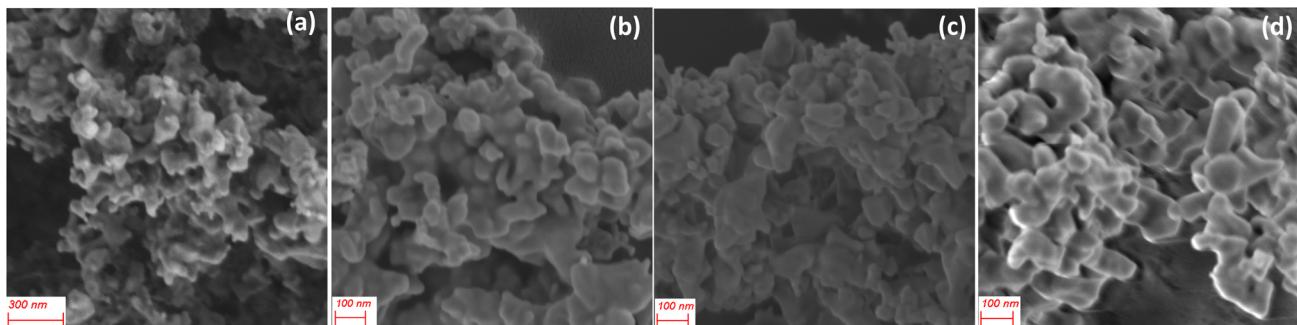


Fig. 4 SEM images of (a)  $\text{CoSb}_3$  obtained at optimized reaction conditions (1 : 2.8 equivalents of reactants and reaction duration of 72 h), recorded using an SE detector and SEM images showing morphology evolution from cassini oval to plate-like shape over the increment of the reaction duration, (b) 24 h, (c) 48 h and (d) 72 h, recorded using an in lens detector.

respectively could be identified in the SAED pattern. Peaks corresponding to these planes are observed at  $19.6^\circ$ ,  $31.2^\circ$ ,  $37.1^\circ$ ,  $42.3^\circ$ , and  $51.5^\circ$  in the PXRD pattern. The peak with the highest intensity in PXRD at  $31.2^\circ$ , followed by the next intense peak at  $35.4^\circ$  with  $hkl$  values of (013) and (123), could be traced in the SAED pattern. On determining the interplanar distance,

spots in the FFT image (Fig. 5(d)) of the area shown in Fig. 5(c) correspond to the (211), (123), (330), (332), and (431) planes according to the ICDD 01-078-0976 pattern. The peaks of the planes (211) and (332) were observed at  $24^\circ$  and  $47.1^\circ$  in the PXRD pattern with interplanar distances of  $3.6 \text{ \AA}$  and  $1.9 \text{ \AA}$  respectively.

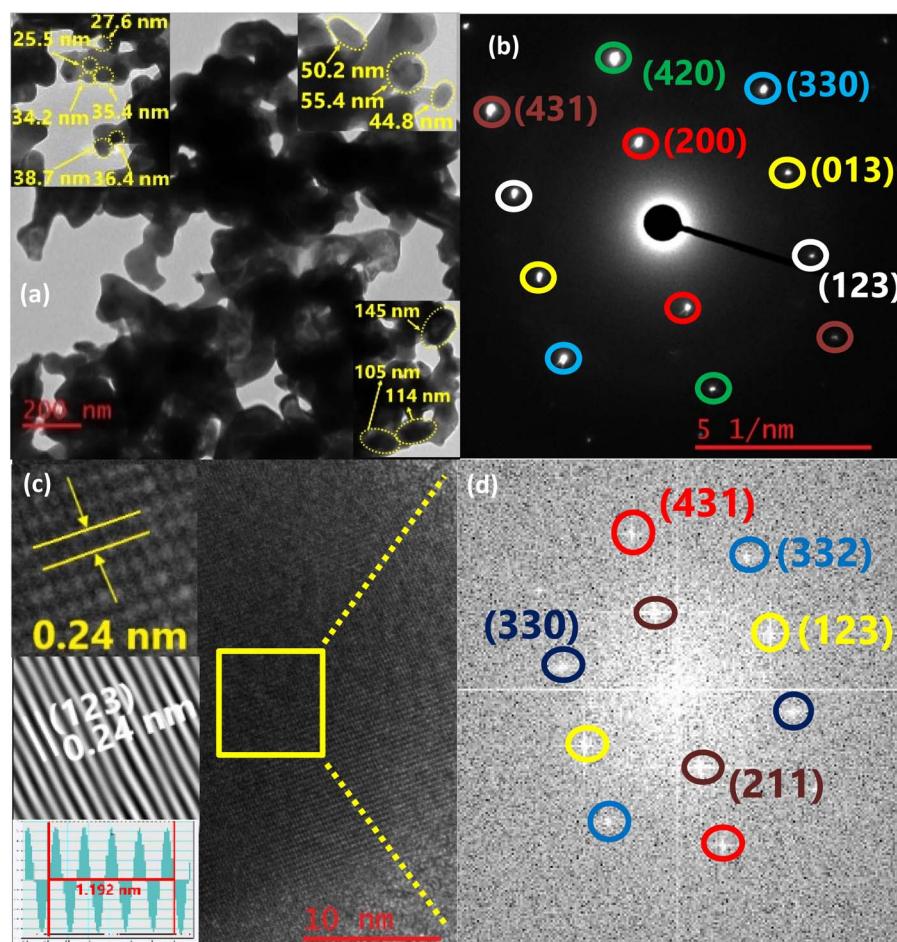
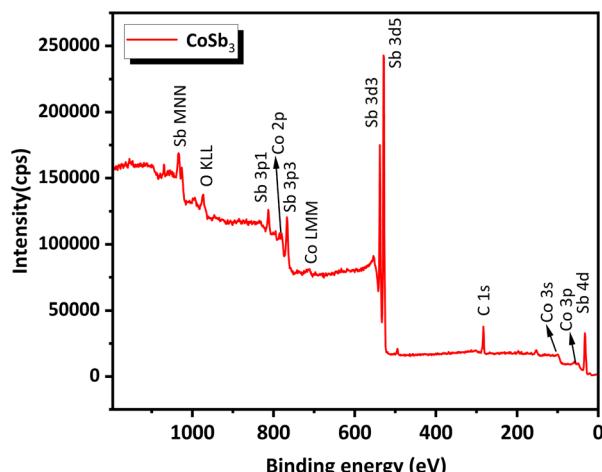
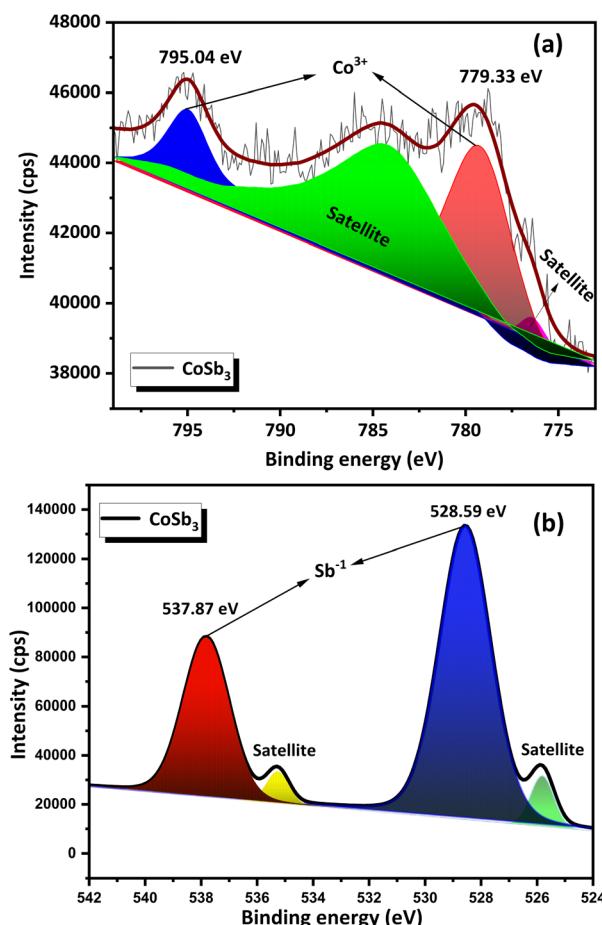


Fig. 5 (a) TEM image of  $\text{CoSb}_3$ , with particles of different morphology in the insets, top left and right-cassini oval-shaped particles, and bottom right-plate-like particles (b) SAED pattern with planes indexed (c) HRTEM image with insets, top left-marked lattice plane, middle-inverse FFT image and the bottom left-simulated calculation result of lattice spacing and (d) FFT image of the marked area.



Fig. 6 Survey scan XPS spectra of  $\text{CoSb}_3$ .

The survey scan XPS spectrum (Fig. 6) of the compound contained peaks corresponding to Co and Sb. The standard binding energy values for Co and Sb metals, according to the NIST X-ray Photoelectron Spectroscopy Database, are as follows,  $\text{Co } 2\text{p}_{3/2}$  – 778.15 eV,  $\text{Co } 2\text{p}_{1/2}$  – 793.30 eV,  $\text{Sb } 3\text{d}_{5/2}$  – 528.20 eV, and  $\text{Sb } 3\text{d}_{3/2}$  – 538.00 eV. High-resolution narrow-scan spectra of

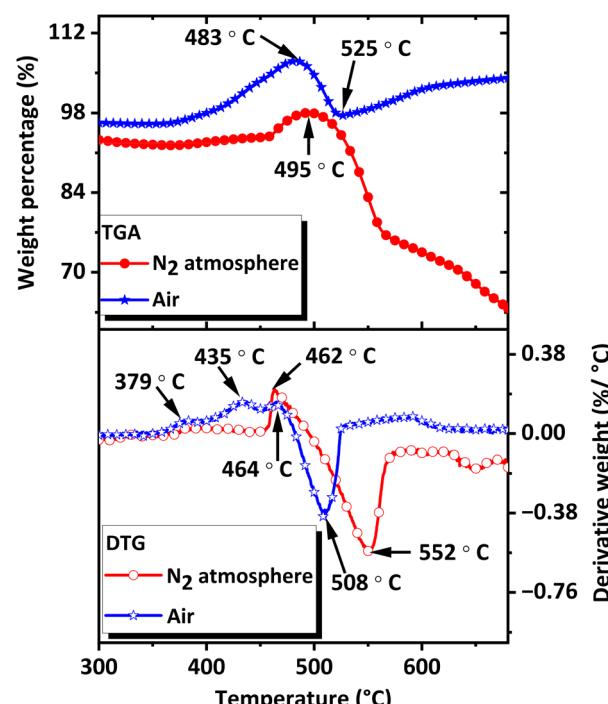
Fig. 7 (a) Narrow scan XPS spectra of Co and (b) Sb in  $\text{CoSb}_3$ .

Co (Fig. 7(a)) exhibit peaks corresponding to the  $\text{Co } 2\text{p}_{3/2}$  state at 779.33 eV and  $\text{Co } 2\text{p}_{1/2}$  at 795.04 eV. This indicates that Co was present in the +3 oxidation state. Satellite peaks were present at 776.47 eV and 784.46 eV. Peaks corresponding to the Sb  $3\text{d}_{5/2}$  and the Sb  $3\text{d}_{3/2}$  were found in the narrow scan spectra of Sb (Fig. 7(b)) at 528.59 eV and 537.87 eV respectively. This indicated that Sb was present in the -1 oxidation state. Satellite peaks were found at 535.26 eV and 525.83 eV. The XPS data show that Co and Sb were in their oxidation states, corresponding to their stoichiometry. The XPS spectra of the compounds matched the previously reported data.<sup>25</sup> An auger peak of oxygen (O KLL) arising from minor quantities of oxygen adsorbed on the CNS surface was observed in the survey scan XPS spectrum at 973.76 eV. The absence of peaks corresponding to the other oxidation states of Co and Sb in the narrow scan spectra indicated the formation of single-phase high-purity  $\text{CoSb}_3$ , confirming the optimization procedure.

### Thermal stability of $\text{CoSb}_3$

The thermal stability of the CNS was evaluated using TGA. The analysis was performed between 30 °C and 700 °C in air and  $\text{N}_2$  atmosphere using approximately 1.5 mg sample at a heating rate of 10 °C min<sup>-1</sup>.

As shown in the TGA-Differential Thermogravimetry (TGA-DTG) plots (Fig. 8),  $\text{CoSb}_3$  is stable up to 455 °C under  $\text{N}_2$  atmosphere and up to 360 °C in air. In a  $\text{N}_2$  atmosphere, a weight gain was observed at 458 °C, indicating oxidation caused by trace amounts of oxygen present in the furnace and gas. The weight gain continued until 495 °C, after which the sample started to lose weight. The weight loss indicates the formation of volatile products from  $\text{CoSb}_3$  and oxidized

Fig. 8 TGA-DTG curves of  $\text{CoSb}_3$  under air and  $\text{N}_2$  atmosphere.

products. In air, multistep weight gain occurred, with weight gain rates peaking at 379 °C, 435 °C, and 464 °C. The weight gain peak observed at 464 °C was followed by a weight loss peak at 508 °C. The more pronounced weight gain observed in air was attributed to the greater extent of oxidation in air. The multiple weight gains were attributed to the oxidation of  $\text{CoSb}_3$ , Co, and Sb to form various oxides along with the formation of intermetallic compounds with oxygen. Oxidation was followed by weight loss, indicating the volatile nature of the decomposition products formed after the oxidation stage and the possible sublimation of Sb formed after the decomposition of  $\text{CoSb}_3$ . Weight loss and decomposition is over at approximately 525 °C in air and around 567 °C in a  $\text{N}_2$  atmosphere. The products formed during and after the oxidation and decomposition stages were analyzed to determine the degradation mechanism of  $\text{CoSb}_3$  at elevated temperatures. The thermal stability of CNS in  $\text{N}_2$  atmosphere was further revealed by DTA (Fig. S5†), and DSC (Fig. S6†) curves.

### Degradation mechanism and kinetic analysis

Details of the kinetic computations are provided in the ESI.† For the kinetic study, TGA analysis was performed at four different heating rates: 4 °C min<sup>-1</sup>, 6 °C min<sup>-1</sup>, 8 °C min<sup>-1</sup>, and 10 °C min<sup>-1</sup> (Fig. 9) in air at a flow rate of 40 mL min<sup>-1</sup> using approximately 1.5 mg of sample for each run. The corresponding DTG curves are shown in the ESI (Fig. S4).†

The extent of conversion ( $\alpha$ ) was calculated from the weight change data obtained from TGA analysis using the equation  $\alpha = (m_0 - m_t)/(m_0 - m_f)$ . Where  $m_0$  is the initial mass,  $m_t$  the mass at time  $t$ , and  $m_f$  the final mass. The extent of conversion was calculated separately for the weight gain (oxidation stage from 360 to 480 °C) and weight loss (decomposition stage from 480 to 525 °C). The dependence of the extent of conversion of oxidation and the extent of conversion of degradation on temperature is shown in the ESI (Fig. S7 and S8).†

The variation in the apparent activation energy ( $E_\alpha$ ) with the extent of conversion ( $\alpha$ ) for oxidation is shown in Fig. 10 and the

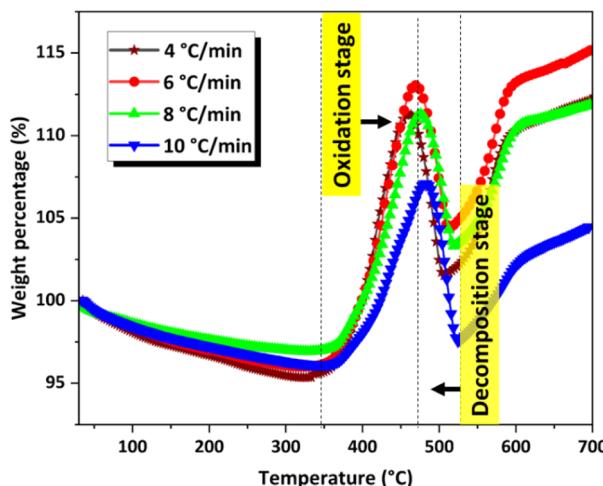


Fig. 9 TGA curves of  $\text{CoSb}_3$  in air at different heating rates.

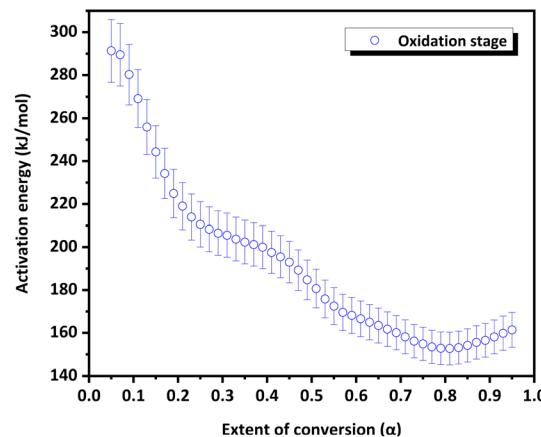


Fig. 10 Extent of conversion versus activation energy curve of the  $\text{CoSb}_3$  oxidation stage.

decomposition is shown in Fig. 11. Combined  $E_\alpha$  vs. temperature curve and combined  $\alpha$  vs.  $E_\alpha$  curve for the oxidation and decomposition stages are given in the ESI (Fig. S9 and S10).† The data obtained were consistent with the reported data, where the activation energy for decomposition was 170–200 kJ mol<sup>-1</sup>.<sup>21</sup> For the oxidation stage (Fig. 10), as the extent of conversion increases from 0.1 to 0.2, the activation energy decreased sharply from 273 kJ mol<sup>-1</sup> to 223 kJ mol<sup>-1</sup>.  $E_\alpha$  decreased gradually from 208 to 200 kJ mol<sup>-1</sup> between  $0.27 \leq \alpha \leq 0.37$ . A steeper decrease was observed from 200 kJ mol<sup>-1</sup> to 169 kJ mol<sup>-1</sup> as  $\alpha$  increased from 0.37 to 0.57. This was followed by a gradual decrease to 153 kJ mol<sup>-1</sup> at  $\alpha = 0.8$ , after which it increased slightly. The decrease in the activation energy for oxidation indicated the instability of  $\text{CoSb}_3$  in an oxygen-rich atmosphere. For the decomposition stage (Fig. 11) between  $0.1 \leq \alpha \leq 0.8$ ,  $E_\alpha$  increases uniformly. Beyond  $\alpha = 0.8$ ,  $E_\alpha$  remained almost constant. The increase in the activation energy from 188 to 237 kJ mol<sup>-1</sup> can be attributed to the interconversion of low-stability products formed during oxidation, to stable oxides.

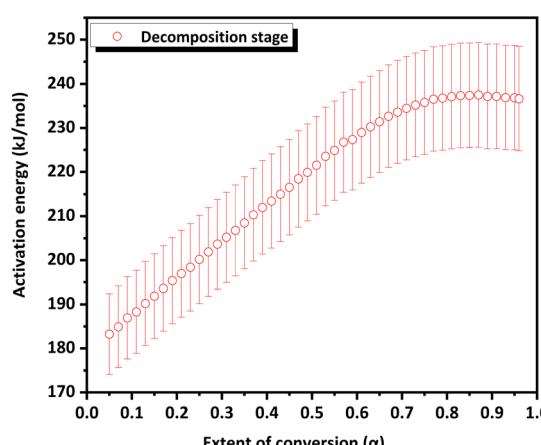


Fig. 11 Extent of conversion versus activation energy curve of the  $\text{CoSb}_3$  decomposition stage.



To gain more insight into the processes occurring, the residue from TG analysis in air and N<sub>2</sub> atmosphere was collected at different stages. The first residue sample was collected after the TG analysis from room temperature to the temperature of maximum weight gain and is hereafter referred to as CNS-OA (CNS-oxidized residue, air) and CNS-ON (CNS-oxidized residue, N<sub>2</sub> atmosphere). The second residue sample was collected after conducting TGA from room temperature to the temperature of maximum weight loss referred to hereafter as CNS-DA (CNS-degraded residue, air) and CNS-DN (CNS-degraded residue, N<sub>2</sub> atmosphere), and the third residue sample after the complete run from room temperature to 700 °C, referred to hereafter as CNS-FA (CNS-full temperature range residue, air) and CNS-FN (CNS-full temperature range residue, N<sub>2</sub> atmosphere). The PXRD analysis (Fig. 12) of CNS-OA showed peaks corresponding to CoSb<sub>3</sub> (ICDD 01-078-0976), Sb<sub>2</sub>O<sub>5</sub> (ICDD 00-050-1376), Sb<sub>2</sub>O<sub>4</sub> (ICDD 01-073-1735), Co<sub>3</sub>O<sub>4</sub> (ICDD 01-080-1533), (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub> (ICDD 01-074-1857), and Sb<sub>2</sub>O<sub>3</sub> (ICDD 00-042-1466). The PXRD data of CNS-ON (Fig. 13) sample showed peaks of CoSb<sub>2</sub>O<sub>6</sub> (ICDD 01-084-2062), Sb<sub>2</sub>O<sub>5</sub>, Sb<sub>2</sub>O<sub>4</sub>, Co<sub>3</sub>O<sub>4</sub>, Sb<sub>2</sub>O<sub>3</sub>, Sb<sub>6</sub>O<sub>13</sub> (ICDD 01-071-1091), and CoSb (ICDD 00-033-097). For CNS-DA, the peaks of all the compounds in CNS-OA, except CoSb<sub>3</sub> and (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub>, were observed. CNS-DN exhibited peaks for all compounds present in CNS-ON except Sb<sub>6</sub>O<sub>13</sub>. Additionally, peaks corresponding to (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub> and Sb<sub>4</sub>O<sub>6</sub> were also observed in CNS-DN. The CNS-FA sample exhibited peaks corresponding to the higher oxides CoSb<sub>2</sub>O<sub>6</sub>, Sb<sub>2</sub>O<sub>5</sub>, and Sb<sub>2</sub>O<sub>4</sub>. Except for CoSb and Sb<sub>4</sub>O<sub>6</sub>, all compounds observed in CNS-DN were observed in CNS-FN. The absence of peaks corresponding to CoSb<sub>3</sub> and (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub> in CNS-DA indicates that the weight loss in the TGA curve corresponds to the direct decomposition of (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub> and CoSb<sub>3</sub>, leading to the formation of volatile Sb. In the N<sub>2</sub> atmosphere, the weight loss corresponds to the decomposition of CoSb<sub>3</sub> and the conversion of Sb<sub>6</sub>O<sub>13</sub> to Sb<sub>2</sub>O<sub>4</sub>. The formation of Sb<sub>4</sub>O<sub>6</sub> in CNS-DN can be attributed to the dimerization of Sb<sub>2</sub>O<sub>3</sub>. The scarcity of oxygen in N<sub>2</sub> atmosphere can act as a driving force for dimerization. As the temperature at which the TGA residues

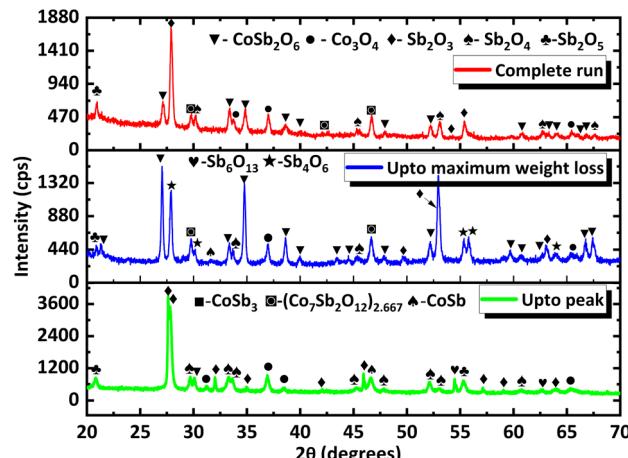


Fig. 13 PXRD data of TGA residues obtained at different stages under a N<sub>2</sub> atmosphere (the stages at which they are collected are provided in the corresponding PXRD pattern).

were collected increased from the temperature of maximum weight gain to the temperature of maximum weight loss and subsequently to 700 °C, the number of compounds observed in the TGA residue from air decreased, indicating rapid interconversion of the oxides formed. Co<sub>3</sub>O<sub>4</sub> (consisting of Co<sup>2+</sup> and Co<sup>3+</sup>) in CNS-DA was converted to CoO by the reduction of Co<sup>3+</sup> to Co<sup>2+</sup>. The formed CoO and (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub> combined with Sb oxides to form CoSb<sub>2</sub>O<sub>6</sub>. Furthermore, Sb<sub>2</sub>O<sub>3</sub> loses volatile Sb to form a more stable, higher oxide Sb<sub>2</sub>O<sub>4</sub>. The presence of (Co<sub>7</sub>Sb<sub>2</sub>O<sub>12</sub>)<sub>2.667</sub>, Sb<sub>2</sub>O<sub>3</sub>, and Co<sub>3</sub>O<sub>4</sub> in CNS-FN indicates that their conversion to the products obtained in CNS-FA (CoSb<sub>2</sub>O<sub>6</sub>, Sb<sub>2</sub>O<sub>5</sub>, and Sb<sub>2</sub>O<sub>4</sub>), as shown in Scheme 3, is restricted owing to the lack of oxygen. The formation of multiple oxides of Sb was attributed to its high affinity for oxygen. In addition, the formation of intermetallic oxides indicated that the oxidation of

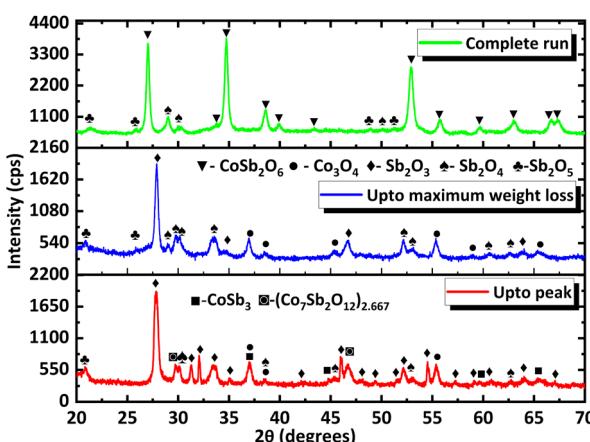
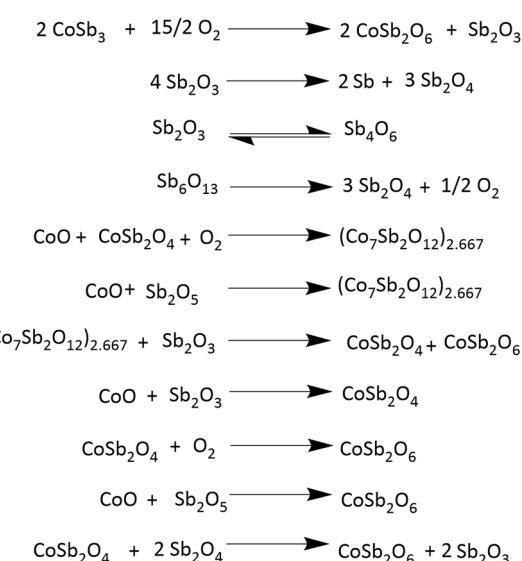


Fig. 12 PXRD data of TGA residues obtained at different stages under air (the stages at which they are collected are provided in the corresponding PXRD pattern).



Scheme 3 Possible reactions occurring in the thermal instability region of CoSb<sub>3</sub>.



$\text{CoSb}_3$  is a complex process involving parallel reactions. This indicates that multiple pathways occurred, which could have led to the formation of products observed in the PXRD pattern. Details of the products observed in the TGA residues are tabulated in the ESI (Table S1).†

To understand the microstructural changes and morphological modifications that occur in  $\text{CoSb}_3$  after degradation, SEM analysis of the residue was performed. SEM analysis revealed a significant change in the CNS morphology after thermal degradation. The change in size and morphology can be attributed to the various products formed during the TGA. After oxidation in air (Fig. 14(a) and S3(a)†), the particles agglomerated to form nearly spherical entities with sizes between 130 and 170 nm. The increased rate of nucleation of various phases upon exposure to high temperatures during the TG analysis led to the formation of spherical entities with increased particle size. The increased roughness of the surface of the particles compared with that of the  $\text{CoSb}_3$  surface is attributed to the multidirectional growth of  $\text{CoSb}_2\text{O}_6$ , which is the major phase in the TGA residue in air.<sup>26</sup>

The SEM images of the TGA residue obtained under a  $\text{N}_2$  atmosphere, CNS-FN (Fig. 14(b) and S3(b)†) showed a non-uniform distribution of irregular spherical (115–180 nm) and plate-like (200–300 nm) particles. However, the particle surfaces are smooth, resembling those of  $\text{CoSb}_3$ . Although  $\text{CoSb}_2\text{O}_6$  was present to direct the growth of a rough surface, the other phases formed along with the change in atmosphere influenced the nucleation of particles with different morphologies and smooth surfaces.

In the TEM image of the TGA residue from the air, CNS-FA (Fig. 15(a) and S4†), the particles agglomerated, and the size and shape of the particles underwent a noticeable change. The particles appear as agglomerated nanospheres and nanoflakes. The particle sizes ranged from 100 to 300 nm. The SAED pattern (Fig. 15(b)) shows a spot pattern corresponding to the diffractions from single crystals of the various phases. The lattice planes of all the phases identified in the PXRD pattern can be traced to the SAED pattern. The planes with  $hkl$  values (220) and (222) belonged to  $\text{Sb}_2\text{O}_4$  with an interplanar distance of 3.6 Å and 2.9 Å respectively. The planes of  $\text{CoSb}_2\text{O}_6$ , (110) and (103) had an interplanar distance of 3.2 Å and 2.5 Å. The (511) plane of  $\text{Sb}_2\text{O}_5$  has an interplanar distance of 1.8 Å. For the TGA

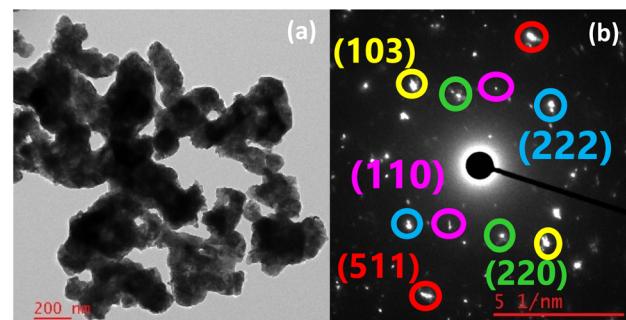


Fig. 15 (a) TEM image and (b) SAED pattern of particles in the TGA residue from room temperature to 700 °C in air.

residue from the nitrogen atmosphere, CNS-FN (Fig. 16(a, b) and S4†), particles of various morphologies, such as nanorods (80–125 nm), nanospheres (40–90 nm), plate-like (40–60 nm), and irregular shapes were observed in the TEM image. A spot pattern corresponding to single crystals of various phases is observed in the SAED data. The planes of  $\text{CoSb}_2\text{O}_6$ ,  $\text{Sb}_2\text{O}_3$ , and  $\text{Sb}_2\text{O}_5$  are shown in Fig. 16(c) and of  $(\text{Co}_7\text{Sb}_2\text{O}_{12})_{2.667}$  and  $\text{Sb}_2\text{O}_4$  in Fig. 16(d). The planes of  $\text{CoSb}_2\text{O}_6$ , (110), (114), and (310), have corresponding interplanar distances of 3.2, 1.8, and 1.4 Å. The (222) and (622) planes of  $\text{Sb}_2\text{O}_3$  have an interplanar distance of 3.2 Å and 1.6 Å. The (111) plane belongs to  $\text{Sb}_2\text{O}_5$  with an interplanar distance of 5.6 Å. In Fig. 16(d), the (220) plane belongs to  $(\text{Co}_7\text{Sb}_2\text{O}_{12})_{2.667}$  with an interplanar distance of 3 Å, and the (222) plane belongs to  $\text{Sb}_2\text{O}_4$  with an interplanar distance of 2.9 Å.

Based on the literature information<sup>27,28</sup> and the present study, a probable oxidation and decomposition mechanism was

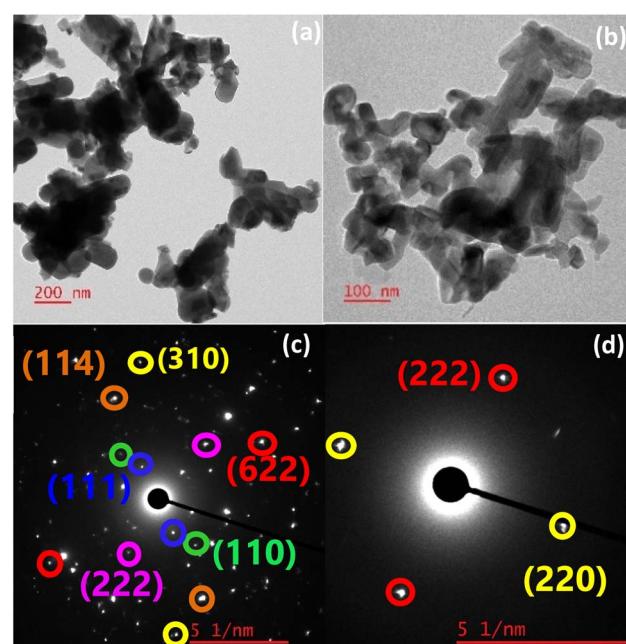


Fig. 16 (a and b) TEM images of the particles with different morphologies in the TGA residue from room temperature to 700 °C in a  $\text{N}_2$  atmosphere and (c and d) SAED pattern.

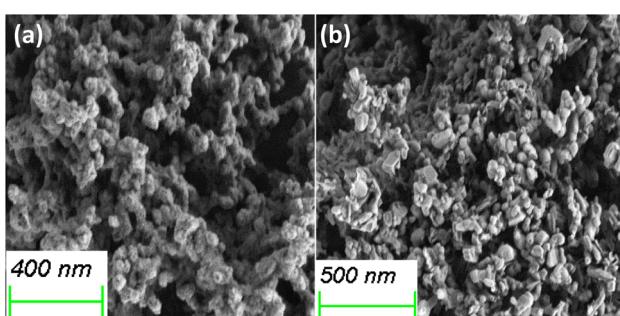


Fig. 14 SEM images of the (a) TGA residue from room temperature to 700 °C in air and (b)  $\text{N}_2$  atmosphere.



derived, as shown in Scheme 3. Analysis of the TGA residue reinforced the results obtained from the kinetic analysis. The value of  $E_\alpha$  decreases during the oxidation stage. The non-uniformity in the decrease in  $E_\alpha$  could be due to the oxidation of various species occurring at different temperatures, indicating a decrease in the stability of the products formed during oxidation. However, the influence of the sublimation of volatile products, such as Sb, on the  $E_\alpha$  value is apparent. The gradual increase in  $E_\alpha$  beyond  $\alpha = 0.8$  can be due to the initiation of the decomposition of the products formed. During the decomposition stage, an increase in  $E_\alpha$  was observed. The uniformity observed in the increase in  $E_\alpha$  can be attributed to the lower number of species undergoing decomposition than oxidation. No further increase in  $E_\alpha$  was observed beyond  $\alpha = 0.8$ , as decomposition was almost complete.

Furthermore, the weight gain above 520 °C can be attributed to the formation of  $\text{CoSb}_2\text{O}_6$  and interconversion of Sb oxides to  $\text{Sb}_2\text{O}_5$  and  $\text{Sb}_2\text{O}_4$ . In addition, Sb sublimation, which occurs at approximately at 600 °C, further influences the reactions occurring in this temperature range. This indicates that the stability of  $\text{CoSb}_3$  decreases as the oxidation process advances and more stable oxidation products are formed at higher temperatures.

## Conclusions

An optimized solvothermal synthesis of  $\text{CoSb}_3$  nanostructures (CNS) was developed by investigating the effects of reactant concentration, solvent, and reaction duration. The formation of  $\text{CoSb}_3$  proceeded through multiple steps, with  $\text{SbCl}_3$  identified as the limiting reactant during the optimization process. The formation of  $\text{CoSb}_2$  is kinetically controlled, whereas that of  $\text{CoSb}_3$  is thermodynamically controlled. CNS readily undergoes oxidation in air above 360 °C and above 455 °C in a nitrogen ( $\text{N}_2$ ) atmosphere. Thermogravimetric analysis (TGA) of the residues under  $\text{N}_2$  from room temperature to the point of maximum weight gain revealed the presence of  $\text{CoSb}_2\text{O}_6$ ,  $\text{Sb}_2\text{O}_5$ ,  $\text{Sb}_2\text{O}_4$ ,  $\text{Co}_3\text{O}_4$ ,  $\text{Sb}_2\text{O}_3$ ,  $\text{Sb}_6\text{O}_{13}$ , and  $\text{CoSb}$ . Compared to the TGA residues in air, additional peaks corresponding to  $\text{CoSb}_2\text{O}_6$ ,  $\text{Sb}_6\text{O}_{13}$ , and  $\text{CoSb}$  were observed in the  $\text{N}_2$  atmosphere. In air, the interconversion of oxides was rapid, as evidenced by the reduced number of compounds in the residues collected at temperatures increasing from the point of maximum weight gain to maximum weight loss and subsequently to 700 °C. In contrast, under  $\text{N}_2$ , the interconversion was slower owing to limited oxygen availability. As the temperature increased from the point of maximum weight gain to the point of maximum weight loss in  $\text{N}_2$ , peaks corresponding to  $\text{Sb}_6\text{O}_{13}$  disappeared, while peaks for  $(\text{Co}_7\text{Sb}_2\text{O}_{12})_{2.667}$  and  $\text{Sb}_4\text{O}_6$  emerged. This suggests that the weight loss in the TGA curve under  $\text{N}_2$  corresponds to the decomposition of  $\text{CoSb}_3$  and conversion of  $\text{Sb}_6\text{O}_{13}$  to  $\text{Sb}_2\text{O}_4$ , with possible dimerization of  $\text{Sb}_2\text{O}_3$ , leading to the formation of  $\text{Sb}_4\text{O}_6$ . At 700 °C in  $\text{N}_2$ , most compounds, except  $\text{CoSb}$  and  $\text{Sb}_4\text{O}_6$ , were consistent with those observed at the temperature of maximum weight loss, indicating the slow interconversion of oxides in a low-oxygen environment. These findings suggest the need to develop effective methods to prevent oxidation and

suppress Sb sublimation to enable the efficient use of CNS in thermoelectric generators (TEGs) for mid-temperature applications. Although the higher polarity of methanol appears to stabilize the intermediate  $\text{CoSb}_2$  and influence the formation of  $\text{CoSb}_3$ , further studies are needed to establish the specific role of methanol in  $\text{CoSb}_3$  formation.

## Data availability

Most of the data supporting the findings of this study are included in the ESI.† Additional data are available from the corresponding author upon reasonable request.

## Author contributions

The manuscript was written through the contributions of all authors.

## Conflicts of interest

There are no conflicts to declare.

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